NSN 5962-01-202-4653

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-202-4653

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches and 0.310 inches	
Body Height:	
0.185 inches	
Maximum Power Dissipation Rating:	
739.0 milliwatts	
Operating Tempurature Range:	
55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
65.0/+150.0 degrees celsius	
Features Provided:	
Hermetically sealed and programmable and bipolar and schottky	
nclosure Material:	
Ceramic	
nclosure Configuration:	
Dual-in-line	
Dutput Logic Form:	
ransistor-transistor logic	
nput Circuit Pattern:	
I0 input	
Case Outline Source And Designator:	
D-2 mil-m-38510	
erminal Surface Treatment:	
Solder	
/oltage Rating And Type Per Characteristic:	
7.0 volts power source	
Time Rating Per Chacteristic:	
75.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low	/ level
putput	
Memory Device Type:	
Rom	
Memory Capacity:	
Jnknown	
Fest Data Document:	
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).	
Terminal Type And Quantity:	
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

NSN 5962-01-202-4653

Memory Microcircuit - Page 2 of 2

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

